TOSHIBA Photocoupler Photorelay

# TLP592G

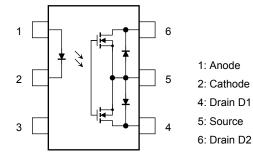
# Telecommunications PBX Modems

The Toshiba TLP592G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a six lead plastic DIP package (DIP6).

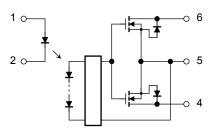
The TLP592G is a bi-directional switch can replace mechanical relays in many applications.

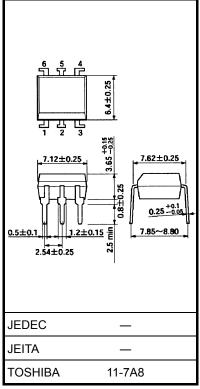
- 6-pin DIP (DIP6)
- 1-Form-A
- Peak Off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 110 mA (max)
- On-state resistance:  $35 \Omega$  (max, t < 1 s)
- On-state resistance: 50  $\Omega$  (max, continuous)
- Isolation voltage: 2500 Vrms (min)

### Pin Configuration (top view)



# Schematic





Weight: 0.4 g (typ.)

#### Absolute Maximum Rating (Ta = 25°C)

	Characteristics		Symbol	Rating	Unit	
LED	Forward current		١ <sub>F</sub>	50	mA	
	Forward current derati (Ta≧25°C)	ing	∆l <sub>F</sub> /°C	-0.5	mA/°C	
	Peak forward current (100 μs pulse, 100 pp	s)	IFP	1	А	
	Reverse voltage		V <sub>R</sub>	5	V	
	Junction temperature		Тj	125	°C	
	Off-state output termin	nal voltage	VOFF	350	V	
	On-state current	A connection		120		
		B connection	I <sub>ON</sub>	120	mA	
		C connection		240		
Detector	On-state current derating (Ta ≧ 25°C)	A connection		-1.2		
		B connection	∆l <sub>ON</sub> /°C	-1.2	mA/°C	
		C connection		-2.4		
	Junction temperature		Tj	125	°C	
Storage temperature range			T <sub>stg</sub>	-55~125	°C	
Operating temperature range			T <sub>opr</sub>	-40~85	°C	
Lead soldering temperature (10 s)			T <sub>sol</sub>	260	°C	
Isolation voltage (AC, 1 min, R.H. $\leq$ 60%) (Note 1)			BVS	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

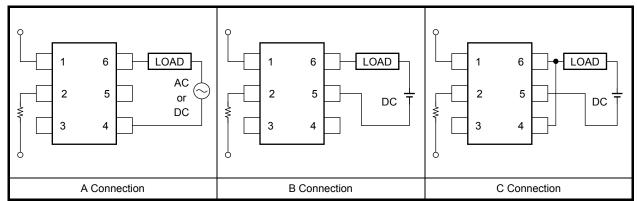
Note 1: Device considered a two-terminal device: LED side pins shorted together, and detector side pins shorted together.

#### **Recommended Operating Conditions**

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V <sub>DD</sub>	_	_	280	V
Forward current	١ <sub>F</sub>	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	100	mA
Operating temperature	T <sub>opr</sub>	-20		65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



# Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I <sub>F</sub> = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz		30	_	pF
Detector	Off-state current	IOFF	V <sub>OFF</sub> = 350 V		_	1	μA
Delector	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	30		pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 120 mA	_	1	3	mA
Return LED current		I <sub>FC</sub>	I <sub>OFF</sub> = 100 μA	0.1	_	_	mA
	A connection		I <sub>ON</sub> = 120 mA, I <sub>F</sub> = 5 mA, t < 1 s	_	25	35	Ω
On-state resistance	A connection		$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	_	35	50	
	B connection		$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	_	28	40	52
	C connection		$I_{ON} = 240 \text{ mA}, I_F = 5 \text{ mA}$		14	20	

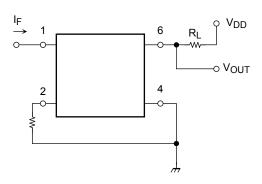
### **Isolation Characteristics (Ta = 25°C)**

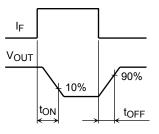
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_{S} = 0 V, f = 1 MHz$	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	$V_{S} = 500 \text{ V}, \text{ R.H.} \le 60\%$	$5  imes 10^{10}$	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	—	5000	_	
		DC, 1 min, in oil	—	5000	_	Vdc

# Switching Characteristics (Ta = 25°C)

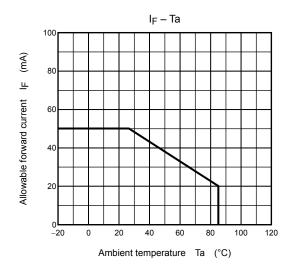
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 200 Ω		0.3	1	me
Turn-off time	tOFF	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ (Note 2)		0.1	1	ms

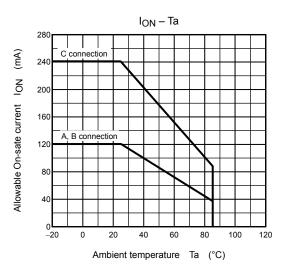
Note 2: Switching time test circuit

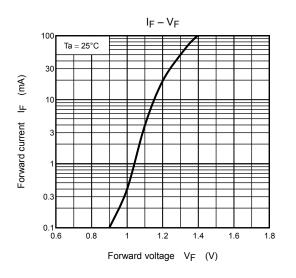


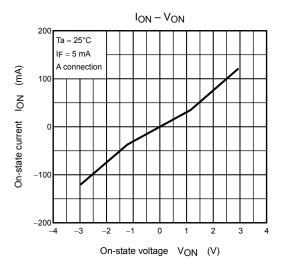


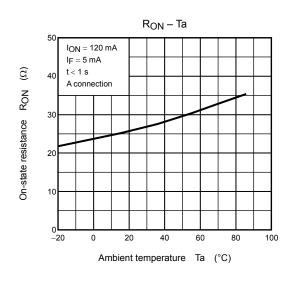
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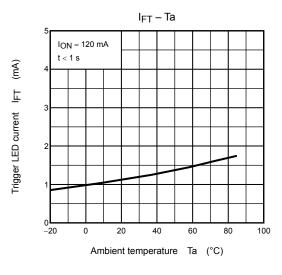




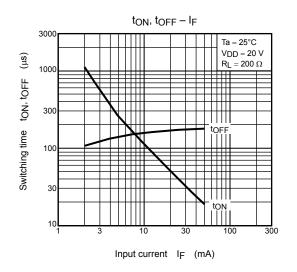


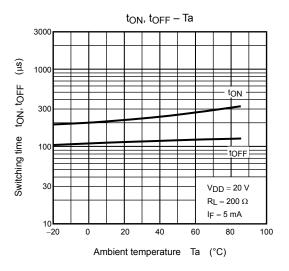


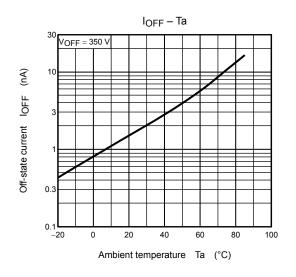




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